

BYV34-600 Dual rectifier diode ultrafast Rev. 02 — 28 September 2018

Product data sheet

1. **Product profile**

1.1 General description

Ultrafast, dual common cathode, epitaxial rectifier diode in a SOT78 (TO-220AB) plastic package.

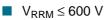
1.2 Features

- Fast switching
- Soft recovery characteristic
- Low switching loss

1.3 Applications

Output rectifiers in high frequency switched-mode power supplies

1.4 Quick reference data



V_F ≤ 1.16 V

Low forward voltage drop High thermal cycling performance

Low thermal resistance

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- I_{O(AV)} ≤ 20 A t_{rr} ≤ 60 ns

Pinning information 2.

Table 1. **Pinning**

Pin	Description	Simplified outline	Symbol
1	anode 1		
2	cathode	mb	
3	anode 2	<u>ک</u> ک	
mb	mounting base; cathode		_ sym084

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3. Ordering information

Table 2. Ordering information									
Type number	Package								
	Name	Description	Version						
BYV34-600	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78						

4. Limiting values

Table 3.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	square waveform; δ = 1.0; T _{mb} \leq 138 °C	-	600	V
I _{O(AV)}	average output current	square waveform; δ = 0.5; T _{mb} ≤ 107 °C; both diodes conducting	-	20	A
I _{FRM}	repetitive peak forward current	t = 25 μ s; square waveform; δ = 0.5; T _{mb} \leq 107 °C; per diode	-	20	A
I _{FSM}	non-repetitive peak forward current	t = 10 ms; sinusoidal waveform; per diode	-	120	A
		t = 8.3 ms; sinusoidal waveform; per diode	-	132	А
T _{stg}	storage temperature		-40	+150	°C
T _i	junction temperature		-	150	°C

5. Thermal characteristics

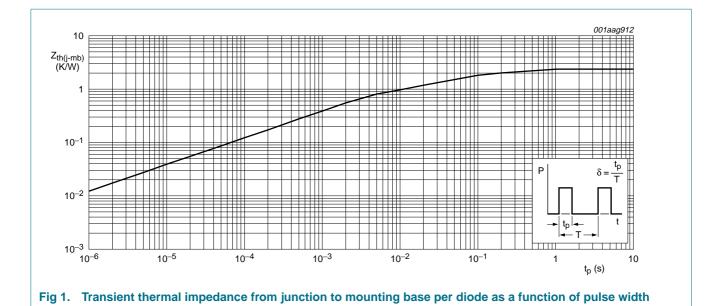
Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	with heatsink compound; per diode; see <u>Figure 1</u>	-	-	2.4	K/W
		with heatsink compound; both diodes conducting	-	-	1.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

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6. Characteristics

Table 5.Characteristics

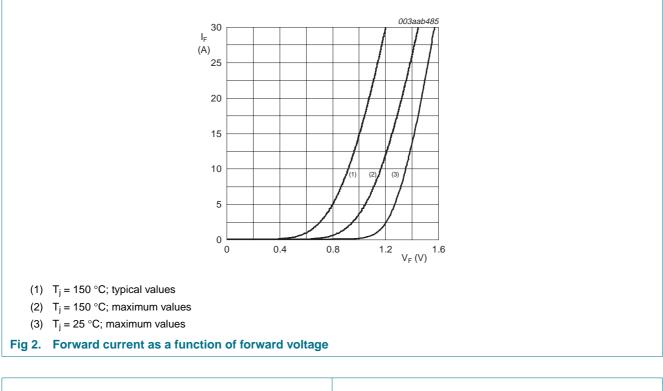
 $T_i = 25 \circ C$ unless otherwise specified.

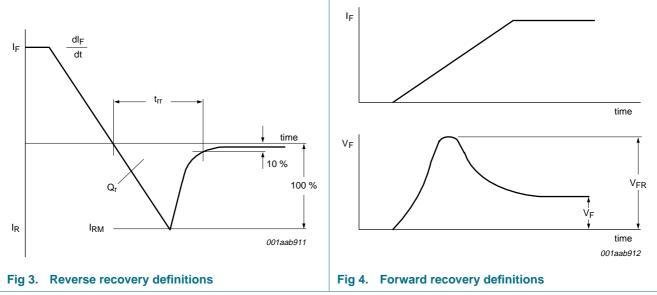
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F forward voltage		I _F = 10 A; T _j = 150 °C; see <u>Figure 2</u>	-	0.92	1.16	V
		I _F = 20 A; see <u>Figure 2</u>	-	1.07	1.48	V
I _R	reverse current	V _R = 600 V	-	10	50	μΑ
		V_R = 600 V; T_j = 100 °C	-	0.2	0.6	mA
Dynamic o	haracteristics					
Qr	recovered charge	$I_F = 2 \text{ A to } V_R \ge 30 \text{ V}; \text{ d}I_F/\text{d}t = 20 \text{ A}/\mu\text{s};$ see Figure 3	-	40	70	nC
t _{rr}	reverse recovery time	$I_F = 1 A \text{ to } V_R \ge 30 \text{ V};$ $dI_F/dt = 100 \text{ A}/\mu\text{s}; \text{ see } \frac{\text{Figure 3}}{2}$	-	50	60	ns
I _{RM}	peak reverse recovery current	$\label{eq:l_F} \begin{array}{l} I_F = 10 \ A \ to \ V_R \geq 30 \ V; \\ dI_F/dt = 50 \ A/\mu s; \ T_j = 100 \ ^\circ C; \\ see \ \underline{Figure \ 3} \end{array}$	-	3	5	A
V _{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 10 A/μs; see <u>Figure 4</u>	-	3.2	-	V

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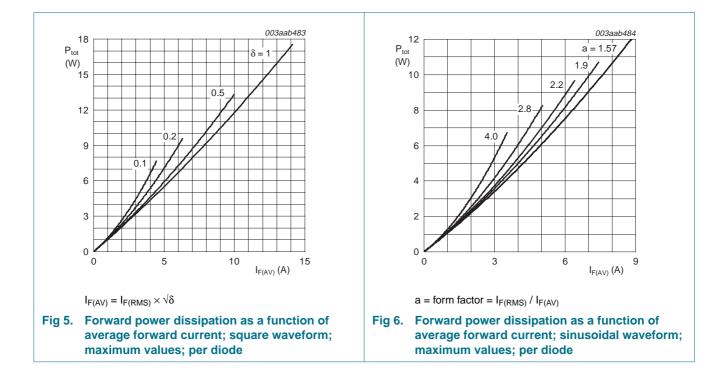




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7. Package outline

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mm	4.7 4.1	1.40 1.25	0.9 0.6	1.45 1.00	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2		
			REFERENCES											OPEAN		ISSUE DATE	
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Fig 7. Package outline SOT78 (3-lead TO-220AB)

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8. Revision history

Table 6. Revision	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV34-600 V.2	20180928	Product data sheet	-	BYV34-600_1
Modification:	Change from NXF	version to WeEn Version		
BYV34-600_1	20071004	Product data sheet	-	-

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9. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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